



### 30V N-CHANNEL ENHANCEMENT MODE MOSFET POWERDI

### **Product Summary**

BV <sub>DSS</sub>	R <sub>DS(ON)</sub> max	I <sub>D</sub> max T <sub>C</sub> = +25°C		
001/	4.4mΩ @ V <sub>GS</sub> = 10V	62A		
30V	5.5mΩ @ V <sub>GS</sub> = 4.5V	56A		

# **Description and Applications**

This MOSFET is designed to meet the stringent requirements of Automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

- Backlighting
- Power Management Functions
- DC-DC Converters

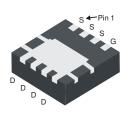
## **Features and Benefits**

- Low R<sub>DS(ON)</sub> Ensures on-state losses are minimized
- Small, form factor thermally efficient package enables higher density end products
- Occupies only 33% of the board area occupied by SO-8 enabling smaller end products
- 100% Unclamped Inductive Switch (UIS) Test in Production
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

### **Mechanical Data**

- Case: PowerDI3333-8
- Case Material: Molded Plastic, "Green" Molding Compound.
   UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 🔞
- Weight: 0.072 grams (Approximate)

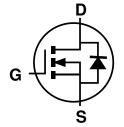
PowerDI3333-8



**Bottom View** 



Top View



**Equivalent Circuit** 

### Ordering Information (Note 5)

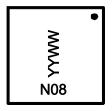
Part Number	Case	Packaging
DMN3008SFGQ-7	PowerDI3333-8	2,000/Tape & Reel
DMN3008SFGQ-13	PowerDI3333-8	3,000/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Refer to http://www.diodes.com/product\_compliance\_definitions.html.
- 5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

## Marking Information

PowerDI3333-8



N08 = Product Type Marking Code YYWW = Date Code Marking YY = Last Two Digits of Year (ex: 16 = 2016) WW = Week Code (01 to 53)



# **Maximum Ratings** (@ $T_A = +25^{\circ}C$ , unless otherwise specified.)

Characteristic	Symbol	Value	Units		
Drain-Source Voltage	V <sub>DSS</sub>	30	V		
Gate-Source Voltage			V <sub>GSS</sub>	±20	V
	Steady State	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	I <sub>D</sub>	17.6 14.1	А
Continuous Drain Current (Note 7) V <sub>GS</sub> = 10V	t<10s	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	I <sub>D</sub>	23.0 18.4	А
	Steady State	$T_C = +25$ °C $T_C = +70$ °C	I <sub>D</sub>	62 50	А
Pulsed Drain Current (10µs pulse, duty cycle = 1%)	I <sub>DM</sub>	80	Α		
Maximum Continuous Body Diode Forward Current	Is	2	Α		
Avalanche Current, L = 0.1mH			I <sub>AS</sub>	45	Α
Avalanche Energy, L = 0.1mH			E <sub>AS</sub>	101	mJ

# Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

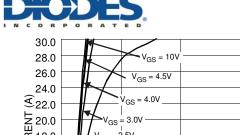
Characteristic	Symbol	Value	Units		
Total Bower Discinction (Note 6)	$T_A = +25$ °C	ם	0.9	W	
Total Power Dissipation (Note 6)	$T_A = +70$ °C	$P_{D}$	0.6		
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	ם	134	°C/W	
Thermal Resistance, Junction to Ambient (Note 6)	t < 10s	$R_{\theta JA}$	79	°C/W	
Total Bower Dissinction (Note 7)		P <sub>D</sub>	2.1	W	
Total Power Dissipation (Note 7)	$T_A = +70^{\circ}C$	PD	1.3	VV	
Thermal Resistance, Junction to Ambient (Note 7)	Steady State	ם	58	°C/W	
Thermal Resistance, Junction to Ambient (Note 7)	t < 10s	$R_{\theta JA}$	34	°C/W	
Thermal Resistance, Junction to Case (Note 7)	R <sub>0</sub> JC	4.8	°C/W		
Operating and Storage Temperature Range	$T_{J_i}T_{STG}$	-55 to +150	°C		

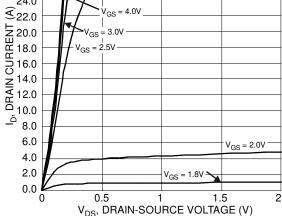
# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

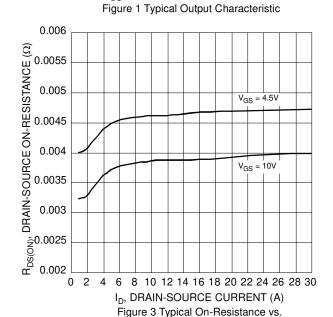
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	30	_	_	V	$V_{GS} = 0V, I_D = 250\mu A$	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	_	_	10	μA	$V_{DS} = 30V, V_{GS} = 0V$	
Gate-Source Leakage			_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 8)	0 0.00						
Gate Threshold Voltage	V <sub>GS(TH)</sub>	1	_	2.3	V	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	
Static Drain-Source On-Resistance		_	3.9	4.4	mΩ	$V_{GS} = 10V, I_D = 13.5A$	
Static Drain-Source On-Resistance	R <sub>DS(ON)</sub>	_	4.6	5.5	11122	$V_{GS} = 4.5V, I_D = 13.5A$	
Diode Forward Voltage	V <sub>SD</sub>		0.75	1.2	V	V <sub>GS</sub> = 0V, I <sub>S</sub> = 1A	
DYNAMIC CHARACTERISTICS (Note 9)		•	•	•	•	•	
Input Capacitance	C <sub>iss</sub>	_	3,690	_	pF	101/1/	
Output Capacitance	Coss	_	530	_	pF	$V_{DS} = 10V, V_{GS} = 0V,$ - f = 1MHz	
Reverse Transfer Capacitance	C <sub>rss</sub>	_	459	_	pF		
Gate Resistance	Rg	_	0.9	_	Ω	$V_{DS} = 0V$ , $V_{GS} = 0V$ , $f = 1MHz$	
Total Gate Charge (V <sub>GS</sub> = 4.5V)	Qg	_	41	_	nC		
Total Gate Charge (V <sub>GS</sub> = 10V)	Qq	_	86	_	nC	٦., ۵., ۵.,	
Gate-Source Charge	Q <sub>gs</sub>	_	9.2	_	nC	$V_{DS} = 24V, I_{D} = 27A$	
Gate-Drain Charge	Q <sub>qd</sub>	_	18.6	_	nC	1	
Turn-On Delay Time	t <sub>D(ON)</sub>	_	5.7	_	ns	$V_{DD} = 15V, V_{GS} = 10V,$ $R_{L} = 1.11\Omega, R_{G} = 4.7\Omega,$ $I_{D} = 13.5A$	
Turn-On Rise Time	t <sub>R</sub>	_	14.0	_	ns		
Turn-Off Delay Time	t <sub>D(OFF)</sub>	_	63.7	_	ns		
Turn-Off Fall Time	t <sub>F</sub>	_	28.4	_	ns		
Reverse Recovery Time	t <sub>RR</sub>	_	19.3	_	ns	1. 40.54 4004(	
Reverse Recovery Charge	Q <sub>RR</sub>	_	10.7	_	$I_F = 13.5A$ , di/dt=100A/µs		

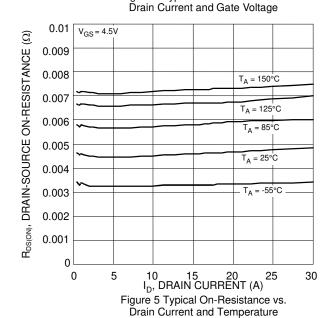
6. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
7. Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.
8. Short duration pulse test used to minimize self-heating effect.
9. Guaranteed by design. Not subject to product testing. Notes:

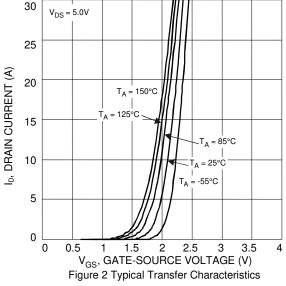
# DMN3008SFGQ

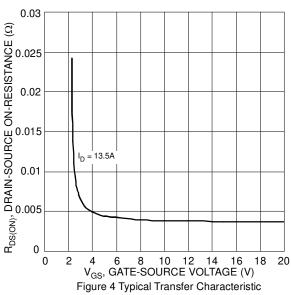












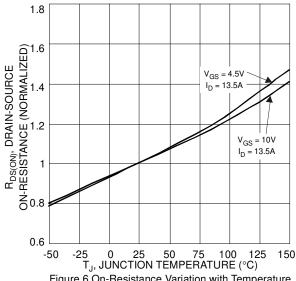
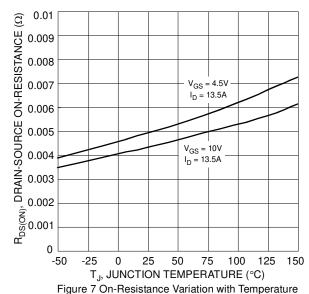
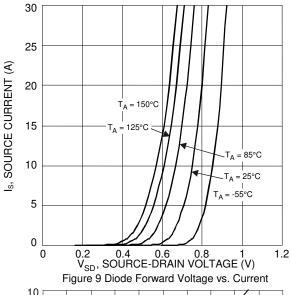


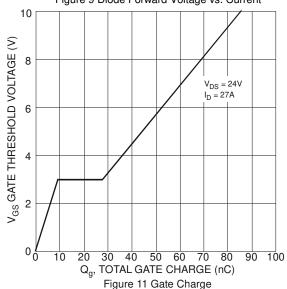
Figure 6 On-Resistance Variation with Temperature

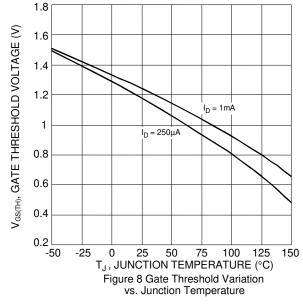












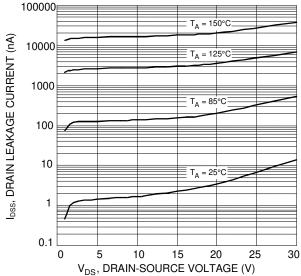
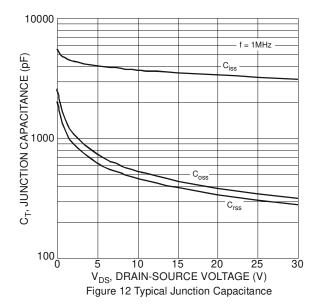
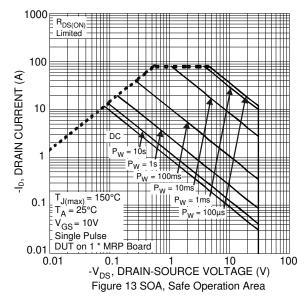
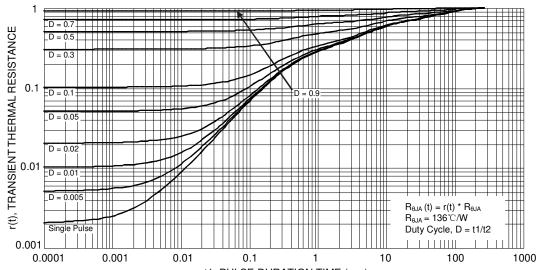


Figure 10 Typical Drain-Source Leakage Current vs. Voltage









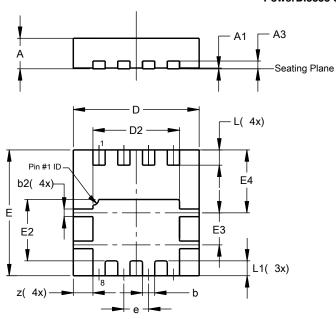
t1, PULSE DURATION TIME (sec) Figure 14 Transient Thermal Resistance



# **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### PowerDI3333-8

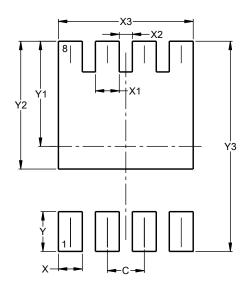


PowerDI3333-8					
Dim	Min	Max	Тур		
Α	0.75	0.85	0.80		
<b>A</b> 1	0.00	0.05	0.02		
<b>A3</b>	-	Ī	0.203		
b	0.27	0.37	0.32		
b2	0.15	0.25	0.20		
D	3.25	3.35	3.30		
D2	2.22	2.32	2.27		
Е	3.25	3.35	3.30		
E2	1.56	1.66	1.61		
E3	0.79	0.89	0.84		
E4	1.60	1.70	1.65		
е	_	_	0.65		
L	0.35	0.45	0.40		
L1	_	_	0.39		
Z	_	_	0.515		
All Dimensions in mm					

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### PowerDI3333-8



Dimensions	Value (in mm)			
С	0.650			
Х	0.420			
X1	0.420			
X2	0.230			
Х3	2.370			
Υ	0.700			
Y1	1.850			
Y2	2.250			
Y3	3.700			



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